## NSN 5961-00-139-6628

No Fiig: A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-139-6628 **Inclosure Material:** Metal **Overall Length:** 0.830 inches **Mounting Facility Quantity: Electrode Internally-electrically Connected To Case:** Cathode **Mounting Method:** Threaded stud **Overall Width Across Flats:** 0.250 inches **Thread Size:** 0.138 inches **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 6.8 breakdown voltage, dc and 7.1 breakdown voltage, dc and 5.7 reverse voltage, instantaneous and 1.0 forward voltage, dc **Current Rating Per Characteristic:** 1350.00 milliamperes voltage regulator diode current **Power Rating Per Characteristic:** 10.0 watts total device dissipation **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Precious Material And Location:** Solder lug plated gold **Test Data Document:** 95542-941-032 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Thread Series Designator:** Unc **Terminal Type And Quantity:** 1 solder stud and 1 tab, solder lug and 1 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:**